# **CETC** 中电国基南方集团有限公司

# WS3A003065E Silicon Carbide Schottky Diode

Features
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- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching
- 175°C Operating Junction Temperature

#### **Benefits**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

### Applications

- Switch Mode Power Supplies
- Power Factor Correction
- AC/DC converters

V <sub>RRM</sub>	=	650	V
I <sub>F</sub> ( T <sub>C</sub> ≤135°C)	=	5	А
Qc	=	8	nC

#### Package





Part Number	Package	Marking
WS3A003065E	TO-252	WS3A003065E

# **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	650	V	$T_{C} = 25^{\circ}C$	
V <sub>RSM</sub>	Surge Peak Reverse Voltage	650	V	$T_{C} = 25^{\circ}C$	
V <sub>R</sub>	DC Blocking Voltage	650	V	$T_{C} = 25^{\circ}C$	
I <sub>F</sub>	Forward Current	11 5 3	A	T <sub>C</sub> ≤ 25°C T <sub>C</sub> ≤ 135°C T <sub>C</sub> ≤ 158°C	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	30	А	$T_C$ = 25 $^\circ C$ , $t_p$ = 8.3ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation	46.8	W	$T_{C} = 25^{\circ}C$	Fig.3
Tc	Maximum Case Temperature	158	°C		
T <sub>J</sub> ,T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to 175	°C		



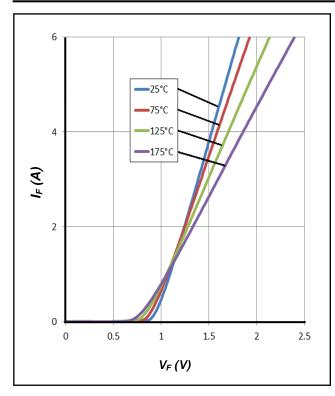
### **Electrical Characteristics**

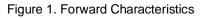
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
N		1.4	1.65	V	$I_F = 3A, T_J = 25^{\circ}C$	
VF	Forward Voltage	1.7	2.3	V	$I_F = 3A, T_J = 175^{\circ}C$	Fig.1
	Deverae Current	1	10	A	$V_{R} = 650V, T_{J} = 25^{\circ}C$	
I <sub>R</sub>	Reverse Current	5	100	μA	$V_{R} = 650V, T_{J} = 175^{\circ}C$	Fig.2
		180			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$	
С	Total Capacitance	18	/	pF	$V_R = 200V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5
		15			$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$	
	Tatal Canaditive Observe	0	,		$V_{R} = 650V, I_{F} = 3A$	
Q <sub>C</sub>	Total Capacitive Charge	8	/	nC	di/dt = 200A/ $\mu$ s, T <sub>J</sub> = 25 $^{\circ}$ C	Fig.4

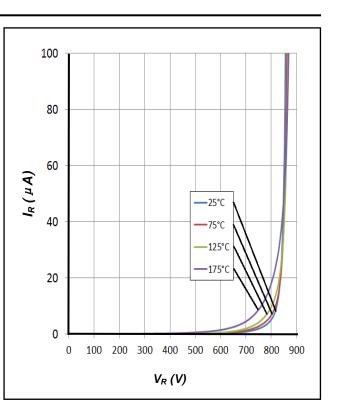
### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>θJC</sub>	Thermal Resistance from Junction to Case	3.2	°C/W	Fig.6
R <sub>0JA</sub>	Thermal Resistance from Junction to Ambient	80	°C/W	
T <sub>sold</sub>	Soldering Temperature	260	°C	

# **Typical Performance**







#### Figure 2. Reverse Characteristics

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# **Typical Performance**

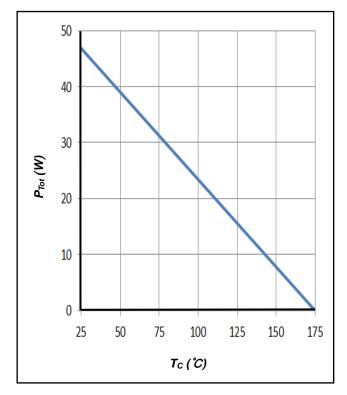
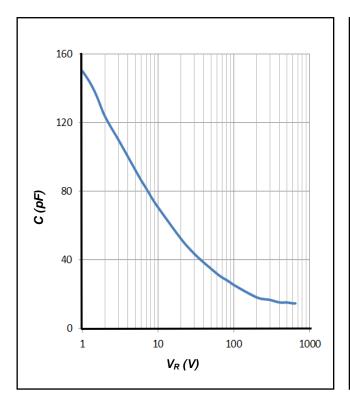
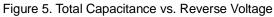


Figure 3. Power Derating





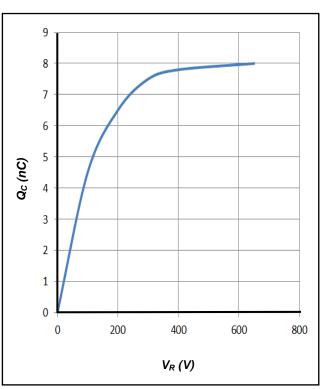
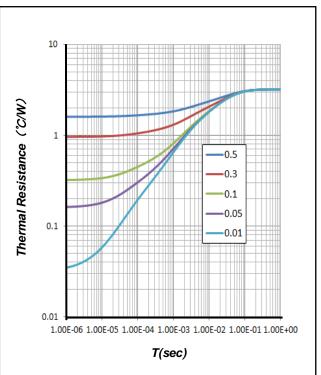
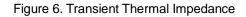


Figure 4. Total Capacitive Charge vs. Reverse Voltage

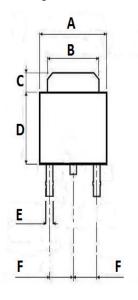




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# **Package Dimensions**

#### Package TO-252

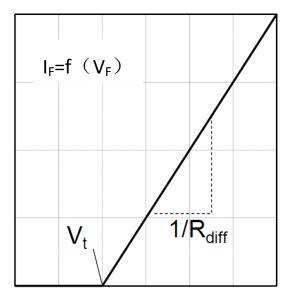


G	
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PI						
Symbol	Min. (mm)	Typ. (mm)	Max. (mm)			
A	6.3	6.5	6.7			
В	5.2	5.3	5.4			
С	1.15	1.25	1.35			
D	5.7	5.9	6.1			
E	0.65	0.7	0.75			
F	2.1	2.3	2.5			
G	2.2	2.3	2.4			
Н	1.45	1.5	1.55			
I	2.9	3.0	3.1			
J	0.45	0.5	0.55			
К	0.9	1	1.1			

### **Simplified Diode Model**

#### Equivalent IV Curve for Model



#### **Mathematical Equation**

$$V_F = V_t + I_F \times R_{diff}$$

$$\begin{split} &\mathsf{V}_{t} = -0.0011 \times \mathsf{T}_{j} + 0.99 \ [\mathsf{V}] \\ &\mathsf{R}_{\mathsf{diff}} = 2.44 \times 10^{-6} \times \mathsf{T}_{j}^{-2} + 3.37 \times 10^{-4} \times \mathsf{T}_{j} + 0.13 \ [\Omega] \end{split}$$

Note:

 $\label{eq:time_state} \begin{array}{l} Tj = Diode \mbox{ Junction Temperature In Degrees Celsius,} \\ \mbox{valid from 25°C to 175°C} \\ I_{F}\mbox{=} \mbox{ Forward Current} \\ \mbox{ Less than 6A} \end{array}$ 

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ADD: No.166 Zhengfang Middle Road, Jiangning District, Nanjing, Jiangsu Province
 Contact Person: YONG YANG, NAN WANG

| TEL: 025-68005861, 13770574989

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